



US 20240178814A1

(19) **United States**

(12) **Patent Application Publication**  
**Goto et al.**

(10) **Pub. No.: US 2024/0178814 A1**

(43) **Pub. Date: May 30, 2024**

(54) **SURFACE ACOUSTIC WAVE DEVICE WITH INTERDIGITAL TRANSDUCER ELECTRODE POSITIONED AT LEAST PARTIALLY IN A PIEZOELECTRIC LAYER**

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(21) Appl. No.: **18/430,047**

(22) Filed: **Feb. 1, 2024**

**Related U.S. Application Data**

(63) Continuation-in-part of application No. 18/229,590, filed on Aug. 2, 2023.

(60) Provisional application No. 63/394,813, filed on Aug. 3, 2022.

**Publication Classification**

(51) **Int. Cl.**

**H03H 9/02** (2006.01)

**H03H 9/64** (2006.01)

(52) **U.S. Cl.**

**CPC .... H03H 9/02952** (2013.01); **H03H 9/02574**

(2013.01); **H03H 9/6453** (2013.01)

(57)

**ABSTRACT**

A surface acoustic wave device is disclosed. The surface acoustic wave device can include a multilayer piezoelectric substrate having a support substrate and a piezoelectric layer over the support substrate. The piezoelectric layer has a first surface facing the support substrate and a second surface opposite the first surface. The surface acoustic wave device can include an interdigital transducer electrode having a first portion and a second portion. The first portion is positioned below the second surface of the piezoelectric layer and the second portion is positioned above the second surface. The first portion has a first sidewall and a second portion has a second sidewall angled relative to the first sidewall.

